


APPLICATION DATA SHEET

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Title of Invention	[METHOD OF FABRICATING FLASH MEMORY CELL]		
Application Type : regular, utility Attorney Docket Number : 12129-US-PA			
Correspondence address: Customer Number: 31561 			
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Inventors Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr. Given Name: Min-San Family Name: Huang Residence: City of Residence: Hsinchu Country of Residence: TW Address-1 of Mailing Address: No. 7, Po-Chuan 3 Rd., Address-2 of Mailing Address: City of Mailing Address: Hsinchu State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail: <u>Inventor 2:</u> Applicant Authority Type: Inventor			

Citizenship:	TW
Name prefix:	Mr.
Given Name:	Pin-Yao
Family Name:	Wang
Residence:	
City of Residence:	Hsinchu City
Country of Residence:	TW
Address-1 of Mailing Address:	3F., No. 25, Lane 167, Dongnan St.,
Address-2 of Mailing Address:	
City of Mailing Address:	Hsinchu City
State of Mailing Address:	
Postal Code of Mailing Address:	300
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	

Attorney Information:

practitioner(s) at Customer Number:

31561



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